

APPLIED PHYSICS EXPRESS Volume 3, Number 6, June 2010

Semiconductors, dielectrics, and organic materials

- 061001 **Characteristics of Thick *m*-Plane InGaN Films Grown on ZnO Substrates Using Room Temperature Epitaxial Buffer Layers**
Kazuma Shimomoto, Atsushi Kobayashi, Kohei Ueno, Jitsuo Ohta, Masaharu Oshima, Hiroshi Fujioka
- 061002 **High Power Blue-Violet Superluminescent Light Emitting Diodes with InGaN Quantum Wells**
Marco Rossetti, Julien Dorsaz, Raffaele Rezzonico, Marcus Duell, Christian Velez, Eric Feltin, Antonino Castiglia, Gatien Cosendey, Jean-François Carlin, Nicolas Grandjean
- 061003 **True Green Laser Diodes at 524 nm with 50 mW Continuous Wave Output Power on *c*-Plane GaN**
Adrian Avramescu, Teresa Lermer, Jens Müller, Christoph Eichler, Georg Bruederl, Matthias Sabathil, Stephan Lutgen, Uwe Strauss
- 061004 **Improved Efficiency of 255–280 nm AlGaIn-Based Light-Emitting Diodes**
Cyril Pernot, Myunghee Kim, Shinya Fukahori, Tetsuhiko Inazu, Takehiko Fujita, Yosuke Nagasawa, Akira Hirano, Masamichi Ippommatsu, Motoaki Iwaya, Satoshi Kamiyama, Isamu Akasaki, Hiroshi Amano
- 061101 **Carrier Density Dependence of Optical Band Gap and Work Function in Sn-Doped In₂O₃ Films**
Yasushi Sato, Toru Ashida, Nobuto Oka, Yuzo Shigesato
- 061301 **High Electron Mobility Ge *n*-Channel Metal–Insulator–Semiconductor Field-Effect Transistors Fabricated by the Gate-Last Process with the Solid Source Diffusion Technique**
Tatsuro Maeda, Yukinori Morita, Shinichi Takagi
- 061302 **Hybrid Laser Activation of Highly Concentrated Bi Donors in Wire- δ -Doped Silicon**
Koichi Murata, Yuhsuke Yasutake, Koh-ichi Nittoh, Kunihiro Sakamoto, Susumu Fukatsu, Kazushi Miki
- 061401 **Formation of High Crystallinity Silicon Films by High Speed Scanning of Melting Region Formed by Atmospheric Pressure DC Arc Discharge Micro-Thermal-Plasma-Jet and its Application to Thin Film Transistor Fabrication**
Shohei Hayashi, Seiichiro Higashi, Hideki Murakami, Seiichi Miyazaki
- 061501 **Observation of Dipole Layer Formed at High-*k* Dielectrics/SiO₂ Interface with X-ray Photoelectron Spectroscopy**
Li Qiang Zhu, Koji Kita, Tomonori Nishimura, Kosuke Nagashio, Sheng Kai Wang, Akira Toriumi
- 061601 ***In situ* Characterization of Photoresist Dissolution**
Toshiro Itani, Julius Joseph Santillan
- 061701 **Finite-Difference Time-Domain Analysis of Laser Action in Cholesteric Photonic Liquid Crystal**
Tatsunosuke Matsui, Masahiro Kitaguchi

Photonics, quantum electronics, optics, and spectroscopy

- 062001 **On-the-Fly Wavelength Conversion of Photons by Dynamic Control of Photonic Waveguides**
Jeremy Upham, Yoshinori Tanaka, Takashi Asano, Susumu Noda
- 062002 **Radial and Azimuthal Polarizer Using a One-Dimensional Photonic Crystal with a Patterned Liquid Crystal Defect Layer**
Kenji Tagashira, Hiroyuki Yoshida, Hitoshi Kubo, Akihiko Fujii, Masanori Ozaki
- 062101 **Large Chip High Power Deep Ultraviolet Light-Emitting Diodes**
Max Shatalov, Wenhong Sun, Yuri Bilenko, Ajay Sattu, Xuhong Hu, Jianyu Deng, Jinwei Yang, Michael Shur, Craig Moe, Michael Wraback, Remis Gaska
- 062201 **Low Temperature Dependence of Oscillation Wavelength in GaAs_{1-x}Bi_x Laser by Photo-Pumping**
Yoriko Tominaga, Kunishige Oe, Masahiro Yoshimoto
- 062301 **A β -Diketonato Ruthenium(II) Complex with High Molar Extinction Coefficient for Panchromatic Sensitization of Nanocrystalline TiO₂ Film**
Shang Gao, Ashraful Islam, Youhei Numata, Liyuan Han

Spintronics, superconductivity, and strongly correlated materials

- 063001 **Direct Imaging of Local Spin Orientation within Artificial Nanomagnets**
Makoto Konoto, Akio Fukushima, Rie Matsumoto, Hitoshi Kubota, Kay Yakushiji, Akihito Sawa, Shinji Yuasa, Koji Ando
- 063002 **Spin Diffusion Characteristics in Magnesium Nanowires**
Hiroshi Idzuchi, Yasuhiro Fukuma, Le Wang, YoshiChika Otani

(Continued on third cover)

(Continued)

- 063101 **High Critical Current Density 4 MA/cm² in Co-Doped BaFe₂As₂ Epitaxial Films Grown on (La,Sr)(Al,Ta)O₃ Substrates without Buffer Layers**
Takayoshi Katase, Hidenori Hiramatsu, Toshio Kamiya, Hideo Hosono
- 063102 **New Iron Arsenide Oxides (Fe₂As₂)(Sr₄(Sc,Ti)₃O₈), (Fe₂As₂)(Ba₄Sc₃O_{7.5}), and (Fe₂As₂)(Ba₃Sc₂O₅)**
Naoto Kawaguchi, Hiraku Ogino, Yasuaki Shimizu, Kohji Kishio, Jun-ichi Shimoyama
- 063103 **Superconductivity Above 40 K Observed in a New Iron Arsenide Oxide (Fe₂As₂)(Ca₄(Mg,Ti)₃O₇)**
Hiraku Ogino, Yasuaki Shimizu, Koichi Ushiyama, Naoto Kawaguchi, Kohji Kishio, Jun-ichi Shimoyama
- 063104 **Macroscopic Quantum Tunneling in a Bi₂Sr₂CaCu₂O_{8+x} Single Crystalline Whisker**
Yuimaru Kubo, Yamaguchi Takahide, Shinya Ueda, Yoshihiko Takano, Youiti Ootuka
- 063201 **Electronic Structure of W-Doped VO₂ Thin Films with Giant Metal-Insulator Transition Investigated by Hard X-ray Core-Level Photoemission Spectroscopy**
Hidefumi Takami, Teruo Kanki, Shigenori Ueda, Keisuke Kobayashi, Hidekazu Tanaka

Device physics

- 064401 **Two-Photon Control of Biexciton Population in Telecommunication-Band Quantum Dot**
Toshiyuki Miyazawa, Tetsuo Koderu, Toshihiro Nakaoka, Katsuyuki Watanabe, Naoto Kumagai, Naoki Yokoyama, Yasuhiko Arakawa

Nanoscale science and technology

- 065101 **Vertical Sheet Array of Carbon Nanotubes Grown on Sapphire Substrates Using Atomic Step Distribution**
Kazuki Yamada, Tomohito Chokan, Shohei Chiashi, Yoshikazu Homma
- 065102 **Adhesive Behavior of Single Carbon Nanotubes**
Yohei Maeno, Atsunori Ishikawa, Yoshikazu Nakayama
- 065103 **Observations of Nanobubble Formation on Carbon Nanotubes**
Andrew J. Slifka, Gurpreet Singh, Damian S. Lauria, Paul Rice, Roop L. Mahajan
- 065201 **Feedback Cooling of a Strained GaAs Micromechanical Beam Resonator**
Takayuki Watanabe, Koji Onomitsu, Hiroshi Yamaguchi
- 065202 **Numerical Simulation of Switching Behavior in Cu/Cu₂S Nanometer-Scale Switch**
Yoshinao Okajima, Yasushi Shibuta, Takashi Tsuchiya, Shu Yamaguchi, Toshio Suzuki
- 065203 **Self-Assembly of Symmetric GaAs Quantum Dots on (111)A Substrates: Suppression of Fine-Structure Splitting**
Takaaki Mano, Marco Abbarchi, Takashi Kuroda, Brian McSkimming, Akihiro Ohtake, Kazutaka Mitsuishi, Kazuaki Sakoda
- 065204 **Giant Peltier Effect in a Submicron-Sized Cu-Ni/Au Junction with Nanometer-Scale Phase Separation**
Atsushi Sugihara, Masaya Kodzuka, Kay Yakushiji, Hitoshi Kubota, Shinji Yuasa, Atsushi Yamamoto, Koji Ando, Koki Takanashi, Tadakatsu Ohkubo, Kazuhiro Hono, Akio Fukushima
- 065205 **High-Resolution Frequency-Modulation Atomic Force Microscopy in Liquids Using Electrostatic Excitation Method**
Ken-ichi Umeda, Noriaki Oyabu, Kei Kobayashi, Yoshiki Hirata, Kazumi Matsushige, Hirofumi Yamada

Crystal growth, surfaces, interfaces, thin films, and bulk materials

- 065801 **Electric Contact Characteristic under Low Load of Silver-Carbon Nanotube Composite Plating Film Corroded Using H₂S Gas**
Masatsugu Fujishige, Mitsuru Sekino, Kazunori Fujisawa, Shingo Morimoto, Kenji Takeuchi, Susumu Arai, Akimasa Kawai

Device processing, fabrication and measurement technologies, and instrumentation

- 066501 **Selective Etching and Polymer Deposition on InP Surface in CH₄/H₂ Reactive Ion Etching Using A New Mask Structure for Application to Submicrometer Pitch Grating**
Norio Yamamoto
- 066502 **Direct Etching of Poly(methyl methacrylate) Using Laser Plasma Soft X-rays**
Shuichi Torii, Tetsuya Makimura, Kouta Okazaki, Daisuke Nakamura, Akihiko Takahashi, Tatsuo Okada, Hiroyuki Niino, Kouichi Murakami

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